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Simplifying System Integration™





DESCRIPTION

The Teridian 73S8010C is a single smart card interface IC. It provides full electrical compliance with ISO-7816-3 and EMV 4.0 specifications.

Interfacing with the host is done through the two-wire I2C bus. Data exchange with the card is managed from the system controller using the I/O line (and eventually the auxiliary I/O lines).

An on-chip oscillator using an external crystal, or connection to a clock signal coming from the system controller can generate the card clock signal.

The 73S8010C IC incorporates an ISO-7816-3 activation/deactivation sequencer that controls the card signals. Level shifters drive the card signals with the selected card voltage (3 V or 5 V), coming from an internal DC-DC converter.

With its high-efficiency DC-DC converter, the Teridian 73S8010C is a cost-effective solution for any smart card reader application to be powered from a single 2.7 V to 3.6 V power supply.

Hardware support for auxiliary I/O lines, C4 / C8 contacts, is provided.

Emergency card deactivation is initiated upon card extraction or upon any fault generated by the protection circuitry. The fault can be a VDD (digital power supply), a VCC (card power supply), a card over-current, or an over-heating fault.

ADVANTAGES

- Single smart card interface
- The inductor-based DC-DC converter provides higher current and efficiency than the usual charge-pump capacitor-based converters
 - \rightarrow Ideal for battery-powered applications
 - → Suitable for high current cards and SAMs: (100 mA max)
- Power down mode: 2 μA typical
- Small Format (5x5mm) 32-QFN package option

FEATURES

Card Interface:

- Complies with ISO-7816-3 and EMV 4.0
- A DC-DC Converter provides 3V / 5V to the card from an external power supply input
- High-efficiency converter: > 80% @ V_{DD}= 3.3 V, V_{CC} = 5 V and I_{CC} = 65 mA
- Up to 100 mA supplied to the card
- ISO-7816-3 Activation / Deactivation sequencer with emergency automated deactivation on card removal or fault detected by the protection circuitry
- Protection include 2 voltage supervisors that detect voltage drops on card V_{CC} and V_{DD} power supplies
- The V_{DD} voltage supervisor threshold value can be externally adjusted
- True over-current detection (150 mA max.)
- I card detection input
- Auxiliary I/O lines, for C4 / C8 contact signals

• Host Interface:

- Fast mode, 400 kbps l²C slave bus
- 8 possible devices in parallel
- One control register and one status register
- Interrupt output to the host for fault detection
- Crystal oscillator or host clock, up to 27 MHz
- Power Supply:
 - V_{DD}: 2.7 V to 3.6 V
- 6 kV ESD Protection on the card interface
- Package: SO28 or 32QFN

APPLICATIONS

- Set-Top-Boxes, DVD / HDD Recorders: Conditional Access and Pay-per-View slots
- Point of Sales and Transaction Terminals
- EMV slots in cell phones and PDAs

Smart Card Interface

DATA SHEET

April 2009

73S8010C

FUNCTIONAL DIAGRAM

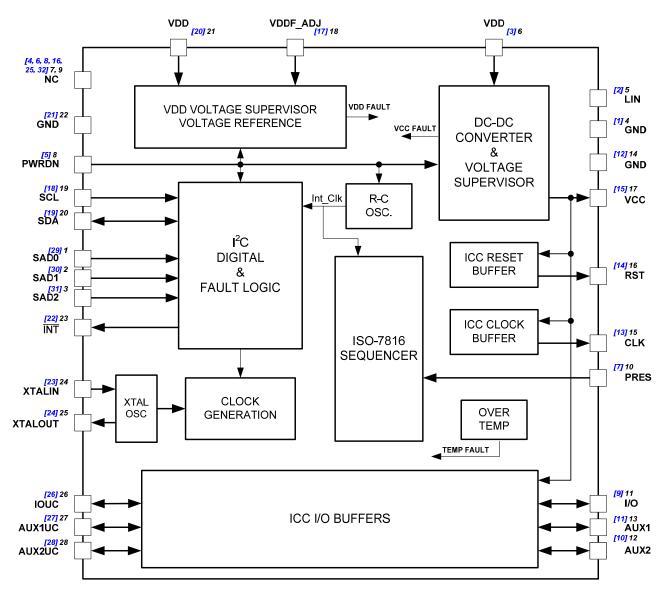


Figure 1: 73S8010C Block Diagram

Pin number reference to SO28 Package [Pin number] reference to 32QFN Package

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1 Pin Description

1.1 Card Interface

Name	Pin (SO)	PIN (QFN)	Description
I/O	11	9	Card I/O: Data signal to/from card. Includes a pull-up resistor to $V_{\mbox{\scriptsize CC}.}$
AUX1	13	11	AUX1: Auxiliary data signal to/from card. Includes a pull-up resistor to $V_{\mbox{\scriptsize CC.}}$
AUX2	12	10	AUX2: Auxiliary data signal to/from card. Includes a pull-up resistor to $V_{\mbox{\scriptsize CC.}}$
RST	16	14	Card reset: provides reset (RST) signal to card.
CLK	15	13	Card clock: provides clock (CLK) signal to card. The rate of this clock is determined by the crystal oscillator frequency and CLKSEL bits in the control register.
PRES	10	7	Card Presence switch: active high indicates card is present. Includes a pull-down resistor.
VCC	17	15	Card power supply: logically controlled by sequencer, output of DC-DC converter. Requires an external filter capacitor to the card GND.
GND	14	12	Card ground.

1.2 Miscellaneous Inputs and Outputs

Name	PIN (SO)	PIN (QFN)	Description
XTALIN	24	23	Crystal oscillator input: can either be connected to a crystal or driven as a source for the card clock.
XTALOUT	25	24	Crystal oscillator output: connected to crystal. Left open if XTALIN is being used as an external clock input.
VDDF_ADJ	18	17	V_{DD} threshold adjustment input: this pin can be used to overwrite a higher V_{DDF} value (that controls deactivation of the card). Must be left open if unused.
NC	7, 9	4, 6, 8, 16, 25, 32	Non-connected pin.

1.3 Power Supply and Ground

Name	PIN (SO)	Pin (QFN)	Description
VDD	6, 21	3, 20	System controller interface supply voltage: supply voltage for internal circuitry and DC-DC converter power supply source.
GND	4	1	DC-DC converter ground.
GND	14	12	Smart Card I/O ground.
GND	22	21	Digital ground.
LIN	5	2	External inductor: Connect external inductor from pin 5 to $V_{\text{DD}}.$ Keep the inductor close to pin 5.

1.4 Microcontroller Interface

Name	PIN (SO)	PIN (QFN)	Description							
INT	23	22		Interrupt output (negative assertion): Interrupt output signal to the processor. A 20 k Ω pull up to V _{DD} is provided internally.						
PWRDN	8	5	activated, a in its lowes	Power Down control input: Active High. When Power Down (PD) mode is activated, all internal analog functions are disabled to place the 73S8010C in its lowest power consumption mode. Must be tied to ground when the power down function is not used.						
SAD0 SAD1 SAD2	1 2 3	29 30 31					s for address selection th allel. Address selections			
SADZ	3	51		SAD2	SAD1	SAD0	I ² C Address (7 bits)			
				0	0	0	0x40			
				0	0	1	0x42			
0 1 0 0x44							0x44			
				0	1	1	0x46			
				1	0	0	0x48			
				1	0	1	0x4A			
				1	1	0	0x4C			
				1	1	1	0x4E			
Pins SAD0 and SAD1 are internally pulled-down a internally pulled-up. The default address when left unconnected is 48h.								D2 is		
SCL	19	18	I ² C clock si	gnal input	t.					
SDA	20	19	I ² C bi-direc	tional seri	al data sig	gnal.				
I/OUC	26	26		System controller data I/O to/from the card. Includes internal pull-up resistor to $V_{\text{DD.}}$						
AUX1UC	27	27	System controller auxiliary data I/O to/from the card. Includes internal pullup resistor to $V_{\mbox{\scriptsize DD}.}$							
AUX2UC	28	28	System cor up resistor		xiliary dat	a I/O to/fro	om the card. Includes int	ternal pull-		

2 Host Interface (I²C Bus)

A fast-mode 400 kHz I²C bus slave interface is used for controlling the device and reading the status of the device via the data pin SDA and clock pin SCL. The bus has 3 address select pins, SAD0, SAD1, and SAD2. This allows up to 8 devices to be connected in parallel.

SAD2	SAD1	SAD0	I ² C Address (7 bits)
0	0	0	0x40
0	0	1	0x42
0	1	0	0x44
0	1	1	0x46
1	0	0	0x48
1	0	1	0x4A
1	1	0	0x4C
1	1	1	0x4E

Table 1: Device Address Selections

Bit 0 of the I²C address is the R/W bit. Refer to Figure 2 and Figure 3 for usage.

2.1 Host Interface Control

Table 2 describes the Host Interface Control Register bits (power-on Reset = 0x00).

Name	Bit	Description							
Start/Stop	0		When set, initiates an activation and a cold reset procedure; when reset, initiates a deactivation sequence.						
Warm reset	1				automatically reset card is declared mu				
5 V and 3 V	2	When set, V_{CC} =	3 V; when re	set, V_{CC} = 5 V.					
Clock Stop	3	When set, card o	clock is stopp	ed. Bit 4 deter	mines the card cloc	k stop level.			
Clock Stop Level	4	When set, card o	When set, card clock stops high; when reset card clock stops low.						
Clksel1	5	Bits 5 and 6 deter	rmine the cloc	k rate to the car	d according to the fo	bllowing table.			
			CLKDIV1	CLKDIV2	Clock Rate				
Clksel2	6		0	0	XTALIN/8				
CIRGEIZ	0	-	0	1	XTALIN/4				
			1	1	XTALIN/2				
		1 0 XTALIN							
I/O enable	7	When set, data is transferred between I/O (AUX1, AUX2) and I/OUC (AUX1UC, AUX2UC); when reset, I/O (AUX1, AUX2) and I/OUC (AUX1UC, AUX2UC) are high impedance.							

Table 2: Host Control Register

I²C-bus Write to the Control Register

The I²C-bus Write command to the control register follows the format shown in Figure 2.

After the START condition, the master sends a slave address. This address is seven bits long followed by an eighth bit, which is an opcode bit (R/W) - a 'zero' indicates the master will write data to the control register. After the R/W bit, the 'zero' ACK bit is sent to the master by the device. The master now starts sending the 8 bits of data to the control register during the DATA bits time. After the DATA bits, the 'zero'

ACK bit is sent to the master by the device. The master should send the STOP condition after receiving the ACK bit.

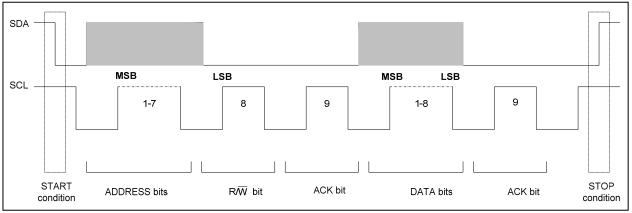


Figure 2: I²C Bus Write Protocol

2.2 Host Interface Status

Table 3 describes the Host Interface Status Register bits (power-on Reset = 0x04).

Name	Bit	Description
PRES	0	Set when the card is present; reset when the card is not present.
PRESL	1	Set when the PRES pin changes state (rising/falling edge); reset when the status register is read. Generates an interrupt when set
I/O	2	Set when I/O is high; reset when I/O is low.
SUPL	3	Set when a voltage fault is detected; reset when the status register is read. Generates an interrupt when set.
PROT	4	Set when an over-current or over-heating fault has occurred during a card session; reset when the status register is read. Generates an interrupt when set.
MUTE	5	Set during ATR when the card has not answered during the ISO 7816-3 time window (40000 card clock cycles); reset when the next session begins or this register is read.
EARLY	6	Set during ATR when the card has answered before 400 card clock cycles; reset when the next session begins or this register is read.
ACTIVE	7	Set when the card is active (V_{CC} is on); reset when the card is inactive.

Table 3: Host Status Register

I²C-bus Read from the Status Register:

The I²C-bus Read Command from the Status Register follows the format shown in Figure 3.

After the START condition, the master sends a slave address. This address is seven bits long followed by an eighth bit, which is the opcode bit (R/W). A 'one' indicates the master will read data from the status register. After the R/W bit, the 'zero' ACK bit is sent to the master by the device. The device now starts sending the 8-bit status register data to the control register during the DATA bits time. After the DATA bits, the 'one' ACK bit is sent to the device. The master should send the STOP condition after receiving the ACK bit.

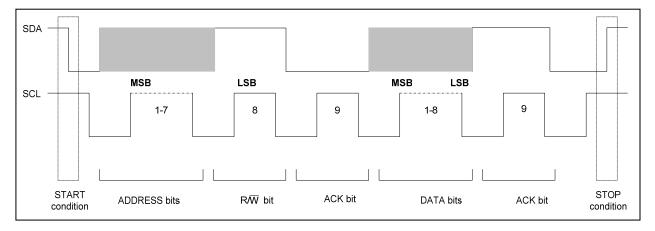


Figure 3: I²C Bus Read Protocol

2.3 I²C-bus Timing

Symbol	Parameter	Conditions	Min.	Тур.	Max.	UNIT
Fsclk	Clock frequency				400	kHz
Tlow	Clock low		1.3			μS
Thi	Clock high		0.6			μS
Thdsta	Hold time START condition		0.6			μs
Tsudat	Data set up time		100			ns
Thddat	Data hold time		5		900	ns
Tsusto	Set up time STOP condition		0.6			μS
Tbuf	Bus free time between a STOP and START condition		1.3			μS

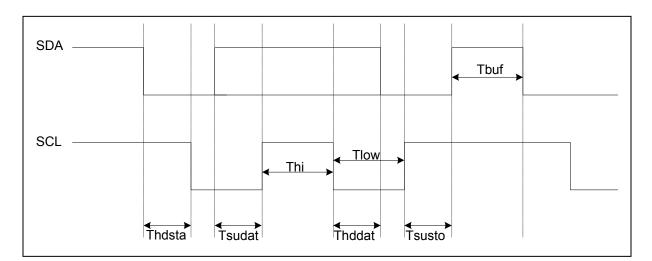


Figure 4: I²C Bus Timing Diagram

3 Oscillator

The Teridian 73S8010C device has an on-chip oscillator that can generate the smart card clock using an external crystal, connected between the XTALIN and XTALOUT pins, to set the oscillator frequency. When the card clock signal is available from another source, it can be connected to the pin XTALIN, and the pin XTALOUT should be left unconnected.

4 DC-DC Converter – Card Power Supply

An internal DC-DC converter provides the card power supply. This converter is able to provide either a 3 V or 5 V card voltage from the power supply applied on the V_{DD} pin. The digital ISO-7816-3 sequencer controls the converter. Bit 2 of the Control register selects the card voltage.

The circuit is an inductive step-up converter/regulator. The external components required are 2 filter capacitors on the power-supply input V_{DD} (100 nF + 10 μ F, next to the LIN pin), an inductor, and an output filter capacitor on the card power supply V_{CC} . The circuit performs regulation by activating the step-up operation when V_{CC} is below a set point of 5.0 or 3.0 volts minus a comparator hysteresis voltage and the input supply V_{DD} is less than the set point for V_{CC} . When V_{DD} is greater than the set point for V_{CC} (V_{DD} = 3.6 V, V_{CC} = 3 V) the circuit operates as a linear regulator. Depending on the inductor values, the voltage converter can provide current on V_{CC} as high as 100 mA.

The circuit provides over-current protection and limits I_{CC} to 150 mA. When an over-current condition is sensed, the circuit initiates a deactivation sequence from the control logic and reports back to the host controller a fault on the interrupt output \overline{INT} .

Choice of the Inductor

The nominal inductor value is 10 μ H, rated for 400 mA. The inductor is connected between pin LIN (pin 5 in the SO package, pin 2 in the QFN package) and the V_{DD} voltage. The value of the inductor can be optimized to meet a particular configuration (I_{CC_MAX}). The inductor should be located on the PCB as close as possible to the LIN pin of the IC.

Choice of the V_{CC} Capacitor

Depending on the applications, the requirements in terms of both V_{CC} minimum voltage and transient currents that the interface must be able to provide to the card vary. Table 4 shows the recommended capacitors for each V_{CC} power supply configuration and applicable specification.

S	pecification Requiren	Appl	ication	
Specification Min V _{cc} Voltage Allowed During Transient Current		Max Transient Current Charge	Capacitor Type	Capacitor Value
EMV 4.0	4.6V	30nA.s	X5R/X7R w/	3.3 μF
ISO-7816-3	4.5V	20nA.s	ESR < 100 mΩ	1 μF

Table 4: Choice of Vcc Capacitor

5 Voltage Supervision

Two voltage supervisors constantly check the level of the V_{DD} and V_{CC} voltages. A card deactivation sequence is forced when a fault occurs for any of these voltage supervisors.

The digital circuitry is powered by the power supply applied on the VDD pin. V_{DD} also defines the voltage range to interface with the system controller. The V_{DD} voltage supervisor is also used to initialize the ISO-7816-3 sequencer at power-on, and to deactivate the card at power-off or when a fault occurs. The voltage threshold of the V_{DD} voltage supervisor is internally set by default to 2.3 V nominal. However, it may be desirable in some applications, to modify this threshold value. The pin VDDF_ADJ (pin 18 in the SO package, pin 17 in the QFN package) is used to connect an external resistor R_{EXT1} to ground to raise the V_{DD} fault voltage to another value, V_{DDF} (refer to Figure 11). The resistor value is defined as follows:

 R_{EXT} = 180 k Ω / (V_{DDF} - 2.33)

An alternative (more accurate) method of adjusting the V_{DD} fault voltage is to use a resistive network of R3 from the pin to supply and R4 from the pin to ground (see Figure 11). In order to set the new threshold voltage, the equivalent resistance must be determined. This resistance value will be designated Kx. Kx is defined as R4/(R4+R5). Kx is calculated as:

 $Kx = (2.649 / V_{TH}) - 0.6042$ where V_{TH} is the desired new threshold voltage.

To determine the values of R4 and R5, use the following formulas.

R5 = 72000 / Kx $R4 = R5^{*}(Kx / (1 - Kx))$

Taking the example above, where a V_{DD} fault threshold voltage of 2.7 V is desired, solving for Kx gives:

 \rightarrow Kx = (2.649 / 2.7) - 0.6042 = 0.377.

Solving for R5 gives: → R5 = 72000 / 0.377 = 191 kΩ. Solving for R4 gives: → R4 = 191000 *(0.377 / (1 – 0.377)) = 115.6 kΩ.

Using standard 1% resistor values gives R5 = 191 k Ω and R4 = 115 k Ω . These values give an equivalent resistance of Kx = 0.376, a 0.3% error.

If the 2.3 V default threshold is used, the VDDF_ADJ pin must be left unconnected.

6 Power Down

A power down function is provided via the PWRDN pin (active high). When activated, the Power Down (PD) mode disables all the internal analog functions, including the card analog interface, the oscillators and the DC-DC converter, to put the 73S8010C in its lowest power consumption mode. PD mode is only allowed in the deactivated condition (out of a card session, when the Start/Stop bit is set to 0 from the I²C host controller).

The host controller invokes the power down state when it is desirable to save power. The signal PRES remains functional in PD mode such that a card insertion sets INT high. The micro-controller must then set PWRDN low and wait for the internal stabilization time prior to starting any card session (prior to setting the Start/Stop bit to 1).

Resumption of the normal mode occurs approximately 10 ms (stabilization of the internal oscillators + reset of the circuitry) after PWRDN is set low. No card activation should be invoked during this 10 ms time period. If a card is present, \overline{INT} can be used as an indication that the circuit has completed its recovery from power down state. \overline{INT} will go high at the end of the stabilization period. Should the Start/Stop be set to 1 during PWRDN = 1, or within the 10 ms internal stabilization / reset time, it will not be taken into account and the card interface will remain inactive. Since Start/Stop is taken into account on its edges, it should be toggled low and high again after the 10 ms to activate a card.

Figure 5 illustrates the sequencing of the PD and Normal modes. PWRDN must be connected to GND if the power down function is not used.

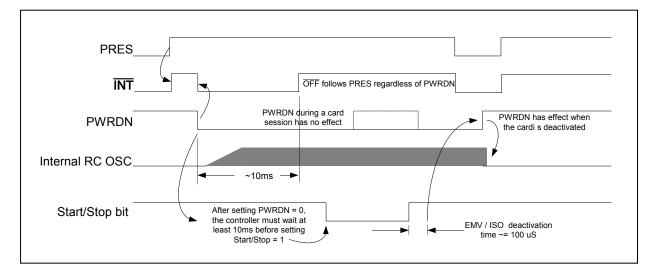


Figure 5: Power Down Mode Operation

7 Over-temperature Monitor

A built-in detector monitors die temperature. When an over-temperature condition occurs (most likely resulting from a heavily loaded card interface, including short circuits), a card deactivation sequence is initiated, and a fault condition is reported to the system controller (bit 4 of the status register is set and generates an interrupt).

8 Activation Sequence

After Power on Reset, the \overline{INT} signal is low until V_{DD} is stable. When V_{DD} has been stable for approximately 10 ms and the \overline{INT} signal is high, the system controller may read the status register to see if the card is present. If all the status bits are satisfactory, the system controller can initiate the activation sequence by writing a '1' to the Start/Stop bit (bit 0 of the Control register).

The following steps and Figure 6 show the activation sequence and the timing of the card control signals when the system controller initiates the Start/Stop bit (bit 0) of the control register:

- 1. Voltage V_{CC} to the card should be valid by the end of t_1 . If V_{CC} is not valid for any reason, then the session is aborted.
- 2. Turn I/O to reception mode at the end of t_1 .
- 3. CLK is applied to the card at the end of t_2 .
- 4. RST (to the card) is set high at the end of t_3 .

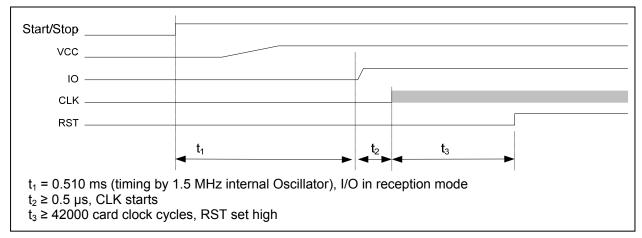


Figure 6: Activation Sequence

9 Deactivation Sequence

Deactivation is initiated either by the system controller resetting the Start/Stop bit, or automatically in the event of hardware faults. Hardware faults are over-current, over-temperature, V_{DD} fault, V_{CC} fault, and card extraction during the session.

The following steps and Figure 7 show the deactivation sequence and the timing of the card control signals when the system controller clears the Start/Stop bit:

- 1. RST goes low at the end of t_1 .
- 2. CLK goes low at the end of t₂.
- 3. I/O goes low at the end of t_3 . Out of reception mode.
- 4. Shut down V_{CC} at the end of time t_4 .

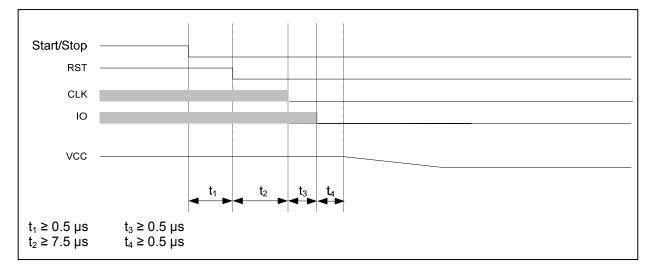


Figure 7: Deactivation Sequence

10 Interrupt

The interrupt is an active low interrupt. It is set low if either a V_{CC} fault or a V_{DD} fault is detected. It is also set low if one of the following status bit conditions is detected:

- Early ATR
- Mute ATR
- Card insert or card extract
- Protection status from Over-current or Over-heating

If the interrupt is set low by the detection of these status bits, then the interrupt is set high when these status bits are read. (READ STATUS DONE)

ANY FAULT		
STATUS BITS	 	
READ STATUS DONE		

Figure 8: FAULT Functions, INT operation

A power-on-reset (POR) event will reset all of the control and status registers to their default states. A V_{DD} fault event does not reset these registers, but it will signal an interrupt condition and by the action of the timer that creates interval "t₁," will not clear the interrupt until V_{DD} is valid for at least the t₁ time. The V_{DD} fault can be considered valid for V_{DD} as low as 1.5 to 1.8 volts. At the lower range of the V_{DD} fault, POR will be asserted.

11 Warm Reset

The 73S8010C automatically asserts a warm reset to the card when instructed through bit 1 of the I^2C Control register (Warm Reset bit). The warm reset length is automatically defined as 42,000 card clock cycles. The bit Warm Reset is automatically reset when the card starts answering or when the card is declared mute.

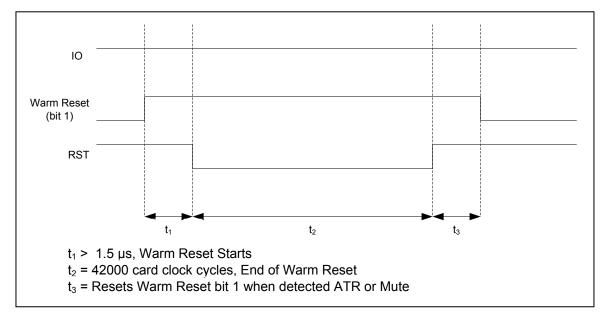


Figure 9: Warm Reset operation

12 I/O Timing

The states of the I/O, AUX1, and AUX2 pins are low after power on reset and they are high when the activation sequencer turns on the I/O reception state. See Section 8 Activation Sequence for more details on when the I/O reception is enabled.

The states of I/OUC, AUX1UC, and AUX2UC are high after power on reset. When the control I/O enable bit (bit 7 of the Control register) is set, the first I/O line on which a falling edge is detected becomes the input I/O line and the other becomes the output I/O line. When the input I/O line rising edge is detected then both I/O lines return to their neutral state. The delay between the I/O signals is shown in Figure 10.

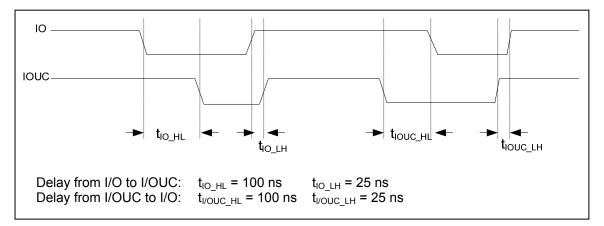


Figure 10: I/O Timing

13 Typical Application Schematic

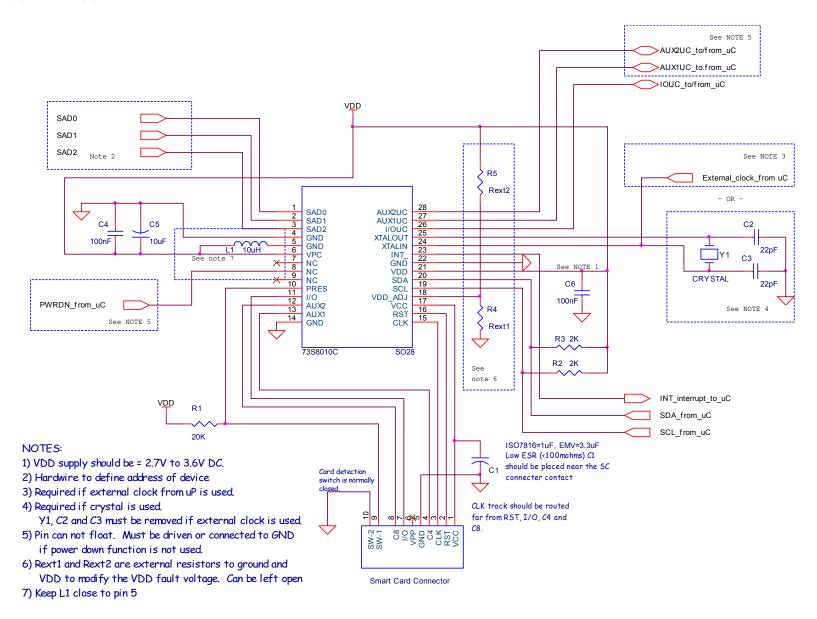


Figure 11: 73S8010C – Typical Application Schematic

14 Electrical Specification

14.1 Absolute Maximum Ratings

Operation outside these rating limits may cause permanent damage to the device.

Parameter	Rating
Supply Voltage V _{DD}	-0.5 to 4.0 VDC
Input Voltage for Digital Inputs	-0.3 to (V _{DD} +0.5) VDC
Storage Temperature	-60 °C to 150 °C
Pin Voltage (except LIN and card interface)	-0.3 to (V _{DD} +0.5) VDC
Pin Voltage (LIN)	-0.3 to 6.0 VDC
Pin Voltage (card interface)	-0.3 to (V _{CC} + 0.5) VDC
ESD Tolerance – Card interface pins	+/- 6 kV
ESD Tolerance – Other pins	+/- 2 kV

ESD testing on Card pins uses the HBM condition, 3 pulses, each polarity referenced to ground.

14.2 Recommended Operating Conditions

Parameter	Rating
Supply Voltage V _{DD}	2.7 to 3.6 VDC
Ambient Operating Temperature	-40 °C to +85 °C
Input Voltage for Digital Inputs	0 V to V _{DD} + 0.3 V

14.3 DC Characteristics: Card Interface

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
Card Pov	ver Supply (V _{cc}) DC-DC Co	onverter				
General	conditions, -40 °C < T < 85 °	$^{\circ}$ C, 2.7 V < V _{DD} < 3.6 V				
		Inactive mode	-0.1		0.1	V
		Inactive mode I _{CC} = 1 mA	-0.1		0.4	V
		Active mode I _{CC} < 65 mA; 5 V	4.75		5.25	V
		Active mode I _{CC} < 65 mA; 3 V	2.8		3.2	V
V _{cc}	Card supply voltage	Active mode single pulse of 100 mA for 2 μs; 5 V, fixed load = 25 mA	4.6		5.25	V
V CC	including ripple and noise	Active mode single pulse of 100 mA for 2 μs; 3 V, fixed load = 25 mA	2.76		3.2	V
		Active mode current pulses of 40 nAs with peak I _{CC} < 200 mA, t < 400 ns; 5 V	4.6		5.25	V
		Active mode current pulses of 40 nAs with peak I _{CC} < 200 mA, t < 400 ns; 3 V	2.76		3.2	V
I _{CCmax}	Maximum supply current to the card	Static load current, V _{CC} > 4.6 or 2.7 V as selected, L=10 μH	100			mA
I _{CCF}	I _{CC} fault current	Short circuit, V_{CC} to ground	100	125	180	mA
V _{SR}	V_{CC} slew rate - Rise rate on activate	C_F on V_{CC} = 1 μF	0.05	0.15	0.25	V/µs
V_{SF}	V _{CC} slew rate - Fall rate on deactivate	C_F on V_{CC} = 1 μF	0.1	0.3	0.5	V/µs
C _F	External filter capacitor (V _{cc} to GND)		0.47	1	3.3	μF
L	Inductor (LIN to V _{DD})			10		μH
Limax	Imax in inductor	V_{CC} = 5 V, I _{CC} = 65 mA, V_{DD} = 2.7 V			400	mA
η	Efficiency	V_{CC} = 5 V, I _{CC} = 65 mA, V_{DD} = 3.3 V		87		%

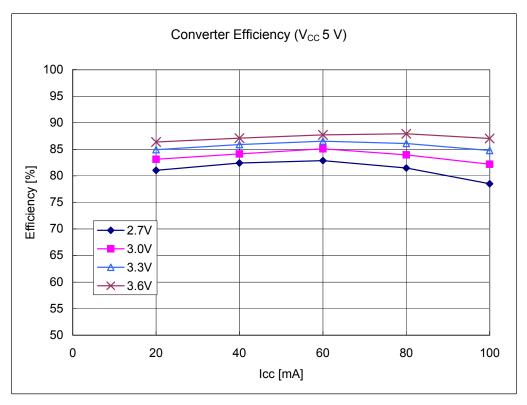
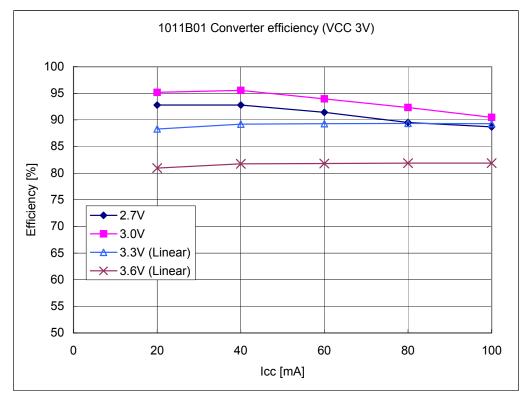
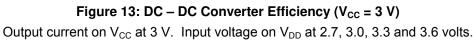


Figure 12: DC – DC Converter Efficiency (V_{cc} = 5 V)

Output current on Vcc at 5 V. Input voltage on V_{DD} at 2.7, 3.0, 3.3 and 3.6 volts.





Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
AUX2UC	Requirements – Data Signals I _{SHORTL} , I _{SHORTH} , and V _{INACT} recents only pertain to I//OUC, AUX	uirements do not pertain to				
V	Output level, high (I/O, AUX1,	I _{OH} = 0	$0.9 V_{CC}$		V _{CC} + 0.1	V
V _{OH}	AUX2)	I _{OH} = -40 μA	$0.75 \: V_{\text{CC}}$		V _{CC} + 0.1	V
V _{он}	Output level, high (I/OUC,	I _{ОН} = 0	$0.9 V_{\text{DD}}$		V _{DD} + 0.1	V
∙он	AUX1UC, AUX2UC)	I _{OH} = -40 μA	$0.75 \; V_{\text{DD}}$		V _{DD} + 0.1	V
V _{OL}	Output level, low	I _{OL} =1 mA			0.3	V
V _{IH}	Input level, high (I/O, AUX1, AUX2)		1.8		V _{CC} + 0.30	V
V _{IH}	Input level, high (I/OUC, AUX1UC, AUX2UC)		1.8		V _{DD} + 0.30	V
V _{IL}	Input level, low		-0.3		0.8	V
V	Output voltage when outside	I _{OL} = 0			0.1	V
V _{INACT}	NACT of session	I _{OL} = 1 mA			0.3	V
I _{LEAK}	Input leakage	$V_{IH} = V_{CC}$			10	μA
1	Input current, low	V _{IL} = 0, CS = 1			0.65	mA
IIL	input current, iow	V _{IL} = 0, CS = 0			5	μA
I _{SHORTL}	Short circuit output current	For output low, shorted to V_{CC} through 33 Ω			15	mA
I _{SHORTH}	Short circuit output current	For output high, shorted to ground through 33 Ω			15	mA
t _R , t _F	Output rise time, fall times	For I/O, AUX1, AUX2, C _L = 80 pF, 10% to 90% For I/OUC, AUX1UC, AUX2UC, CL=50 pF, 10% to 90%			100	ns
t _{IR} , t _{IF}	Input rise, fall times				1	μS
R _{PU}	Internal pull-up resistor	Output stable for >200 ns	8	11	14	kΩ
FD _{MAX}	Maximum data rate				1	MHz
T _{FDIO}	Delay, I/O to I/OUC, I/OUC to I/O			20		ns
C _{IN}	Input capacitance				10	pF

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
Reset and	d Clock for card interface, RST,	CLK				-
V _{OH}	Output level, high	I _{OH} = -200 μA	$0.9 V_{CC}$		V _{CC}	V
V _{OL}	Output level, low	I _{OL} = 200 μA	0		0.3	V
V	Output voltage when outside of	I _{OL} = 0			0.1	V
V _{INACT}	a session	I _{OL} = 1 mA			0.3	V
I _{RST_LIM}	Output current limit, RST				30	mA
I _{CLK_LIM}	Output current limit, CLK				70	mA
		C _L = 35 pF for CLK, 10% to 90%			8	ns
t _R , t _F	Output rise time, fall time	C _L = 200 pF for RST, 10% to 90%			100	ns
δ	Duty cycle for CLK, except for f=f _{XTAL}	C_L =35 pF, $F_{CLK} \leq$ 20 MHz	45		55	%

14.4 DC Characteristics: Digital Signals

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
Digital I/C	except for OSC I/O					
V _{IL}	Input Low Voltage		-0.3		0.8	V
V _{IH}	Input High Voltage		1.8		V _{DD} + 0.3	V
V _{OL}	Output Low Voltage	I _{OL} = 2 mA			0.45	V
V _{OH}	Output High Voltage	I _{ОН} = -1 mA	V _{DD} - 0.45			V
R _{OUT}	Pull-up resistor, INT			20		kΩ
I _{IL1}	Input Leakage Current	$GND < V_{IN} < V_{DD}$	-5		5	μA
Oscillato	(XTALIN) I/O Parameters					
V _{ILXTAL}	Input Low Voltage - XTALIN		-0.3		$0.3 V_{\text{DD}}$	V
V _{IHXTAL}	Input High Voltage - XTALIN		0.7 V _{DD}		V _{DD} +0.3	V
I _{ILXTAL}	Input Current - XTALIN	$GND < V_{IN} < V_{DD}$	-30		30	μA
f _{MAX}	Max freq. Osc or external clock				27	MHz
δin	External input duty cycle limit	t _{R/F} < 10% fin, 45% < δ _{CLK} < 55%	48		52	%

14.5 DC Characteristics: Supply

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
I _{DD}	Supply Current on V _{DD}	Linear mode, ICC=0 I/O, AUX1, AUX2=high		4.9		mA
		Step up mode, ICC=0 I/O, AUX1, AUX2=high		4.7		mA
I _{DD_PD}	Supply Current on V_{DD} in Power Down mode	PWRDN=1, Start/stop bit = 0 All digital inputs driven with a true logical 0 or 1		0.11	2.5	μA

14.6 DC Characteristics: I²C Interface

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
SDA, SCL			•			
V _{IL}	Input Low Voltage		-0.3		0.3* V _{DD}	V
V _{IH}	Input High Voltage		0.7*V _{DD}		V _{DD} + 0.3	V
V _{OL}	Output Low Voltage	I _{OL} = 3 mA			0.40	V
C _{IN}	Pin capacitance				10	pF
I _{IN}	Output High Voltage	I _{он} = -1 mA	V _{DD} - 0.45			V
T _F	Output fall time	C _L = 0 to 400 pF	20 + 0.1*C _L		250	ns
T _{SP}	Pulse width of spikes that are suppressed	Transition from valid logic level to opposite level			50	ns

14.7 Voltage / Temperature Fault Detection Circuits

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
V _{DDF}	V _{DD} fault – V _{DD} Voltage supervisor threshold	No external resistor on VDDF_ADJ pin	2.15		2.4	V
	V _{cc} fault – V _{cc} Voltage	$V_{\rm CC}$ = 5 V	4.20		4.6	V
V _{CCF}	supervisor threshold	V _{CC} = 3 V	2.5		2.7	V
T _F	Die over temperature fault		115		145	°C

15 Mechanical Drawings

15.1 32-pin QFN

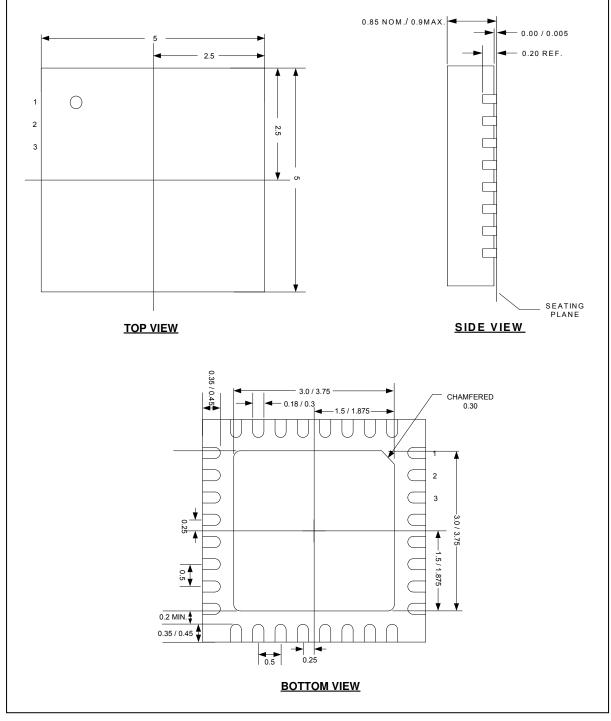


Figure 14: 32-pin QFN Package Drawing

15.2 28-pin SO

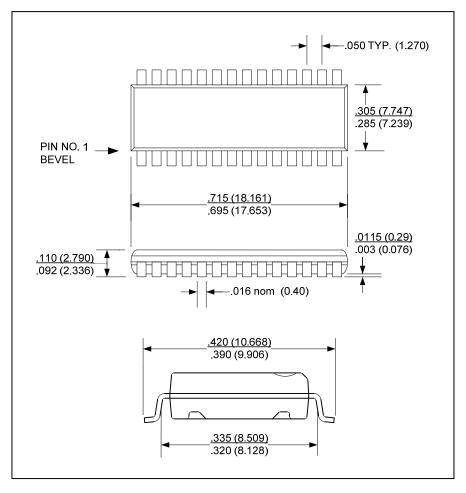
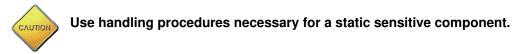


Figure 15: 28-pin SO Package Drawing

16 Package Pin Designation



16.1 32-pin QFN

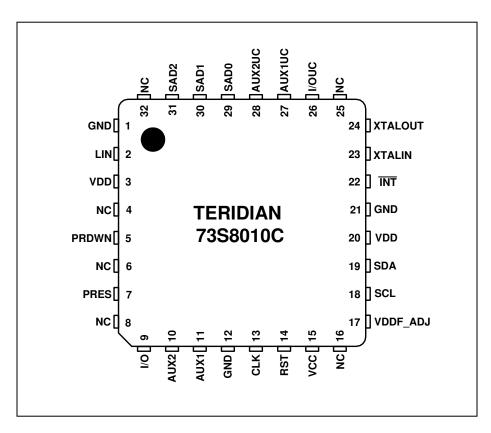


Figure 13: 73S8010C 32-pin QFN Pin Out (Top View)

16.2 28-pin SO

